DOCKET NO. LOTFI 22-2   PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

        Ashraf W. Lotfi, et al.

Serial No.:   09/448,856

Filed: November 23, 1999

For: SiC NMOSFET FOR USE AS A POWER SWITCH AND
               A METHOD OF MANUFACTURING THE SAME

Group No.:   2811

Examiner: Ori Nadav

Commissioner of Patents
  and Trademarks
Washington, D. C. 20231

Sir:

INFORMATION DISCLOSURE STATEMENT

Pursuant to the duty of disclosure under 37 C.F.R. § 1.56, Applicant submits this statement.

This submittal is made in accordance with 37 C.F.R. §§ 1.97 and 1.98 and § 609 of the Manual of

Patent Examining Procedure. The patents, publications and other information herein are listed

below and on the attached Form PTO-1449. Copies of the listed references are submitted herewith.

U.S. Patent No.	Inventor	Date
5,528,482	Rozman	06/18/1996
5,331,533	Smith	07/19/1994
5,309,344	Smith	05/03/1994
4,441,146	Vinciarelli	04/03/1984

Foreign Patent No.	Country	Date
WO 93/24987	PCT	12/09/1993

Applicant hereby expressly reserves the right to swear behind the effective dates of any of the above Patents and to question the relevance and materiality of the Patents and Publications listed herein, in whole, in part, or in combination, subsequent to filing this Information Disclosure Statement.

Respectfully submitted,

HITT GAINES & BOISBRUN, P.C.

Charles W. Gaines
Registration No. 36,804

Date: 8/9/01

Hitt Gaines & Boisbrun, P.C.
P.O. Box 832570
Richardson, Texas 75083
(972) 480-8800